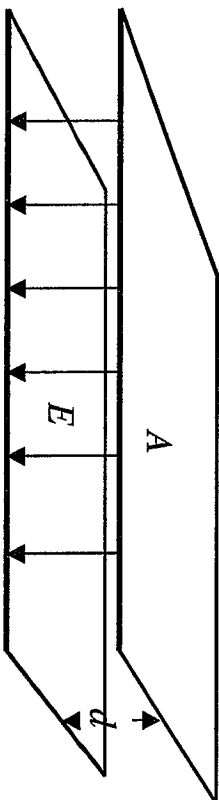


Lecture # 14

9. Capacitors with dielectrics

6. resistivity

## Energy of parallel plate capacitor



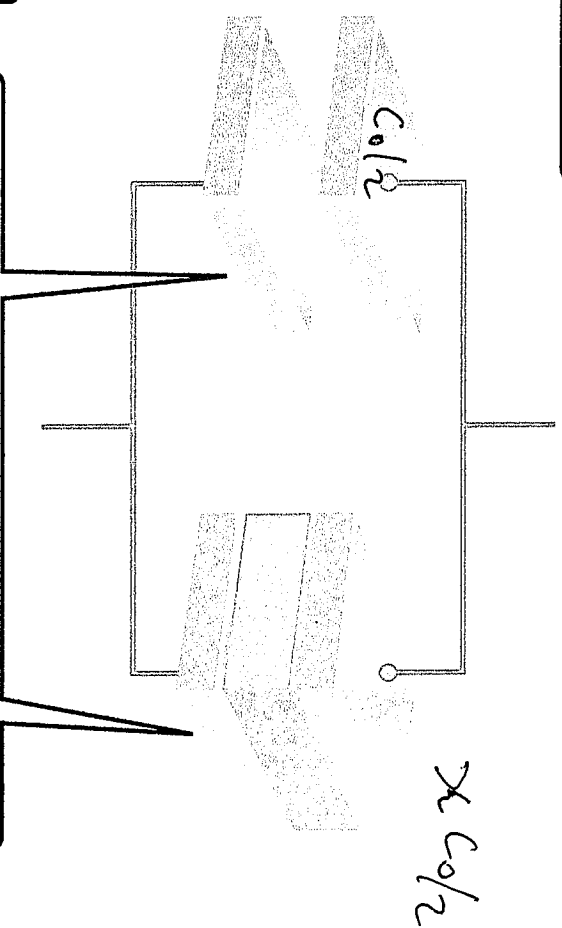
1. What is the Voltage,  $V$ , across the plate?  
a.  $Ed$  ✓ b.  $Ad$  c.  $EdA$
2. What is the magnitude of the charge,  $Q$ , on each plate?  
a.  $Q = \epsilon_0 E$  b.  $Q = \epsilon_0 EA$  c.  $Q = \epsilon_0 EAd$
3. What is the minimum energy required to take a positive charge  $\Delta q$  from the top plate to the bottom plate?  
a.  $\Delta q Ed$  b.  $\Delta q Ad$  c.  $\Delta q EdA$
4. Which of these expressions most thoroughly describes the minimum energy required to place charges  $Q$  and  $-Q$  on each plate?  
a.  $Q Ed/2$  b.  $QV/2$  c.  $Q^2d/2A\epsilon_0$  d.  $\epsilon_0 E^2 Ad/2$  e. all these expressions! ✓

$$V = \int E = \frac{Qd}{\epsilon_0 A}$$

Since plates are equipotentials, this half-filled capacitor...



=



...is equivalent to one empty and one full capacitor connected in parallel.

When the dielectric is inserted:

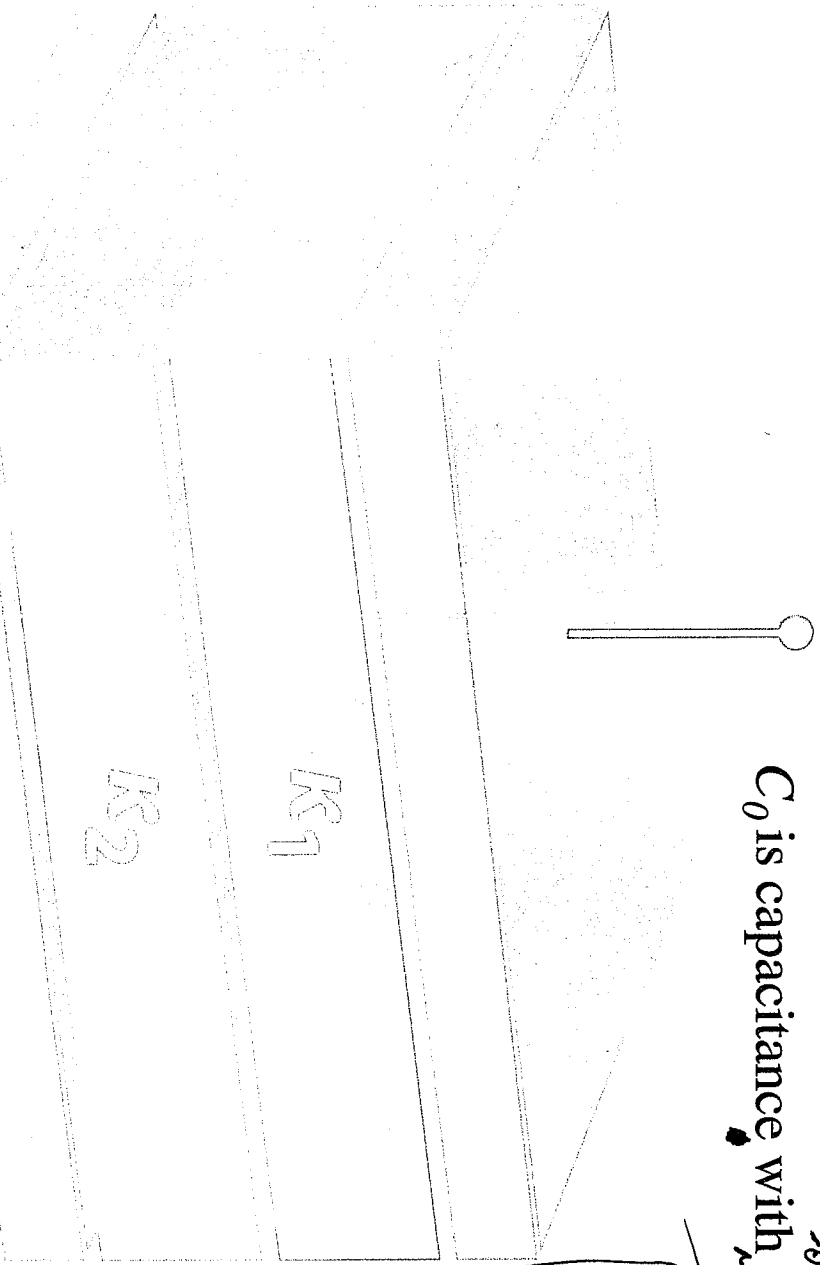
1. The potential will vary on a conducting plate
2. The charge density will vary on a conducting plate.
3. An electric field will be induced tangential to the conducting plate

$$C_{eq} = \frac{C_0}{2} + \frac{\kappa C_0}{2}$$

# Find equivalent capacitance

$C_0$  is capacitance with <sup>out</sup> dielectrics

Plates with the same area, without  $\epsilon$ , have capacitance  $\epsilon C_0$



$$\frac{1}{C_{eq}} = \frac{1}{C_1} + \frac{1}{C_2}$$

$$C_{eq} = \epsilon_0 \epsilon_{eq} \frac{A}{d}$$

- $1/C_{eq} = \frac{1}{\epsilon_0 C_0} + \frac{1}{\epsilon_0 C_0}$
- $C_{eq} = \epsilon_0 C_0 / 2 + \frac{\epsilon_0 C_0}{2}$
- $1/C_{eq} = 1/(\epsilon_0 C_0) + 1/(\epsilon_0 C_0)$

# ELECTRIC CURRENT

(FLOW OF CHARGE PER UNIT OF TIME)

$$I = \frac{\Delta Q}{\Delta t}$$

OR

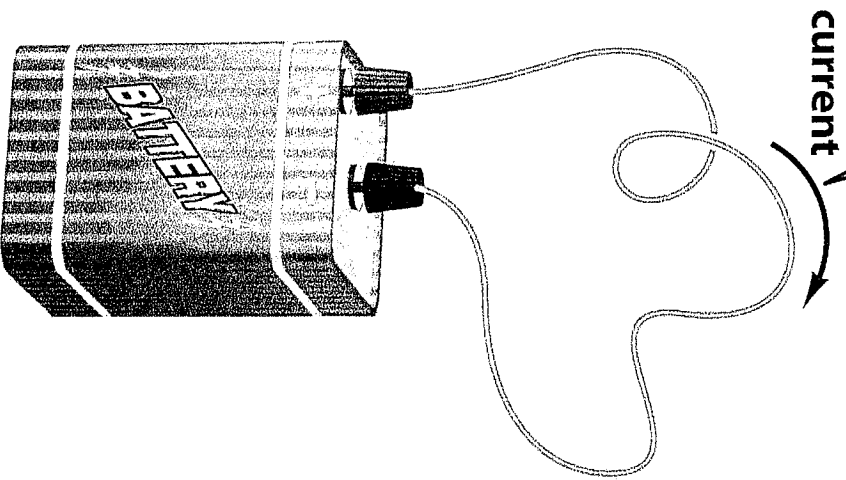
$$I = \frac{dq}{dt}$$

## SI UNIT OF ELECTRIC CURRENT

$$1 \text{ ampere} = 1 \text{ A} = 1 \text{ C/s}$$

(a)

The direction of current always refers to the net flow of positive charge.



(b)

Conventional current direction is opposite to motion of negative charge.

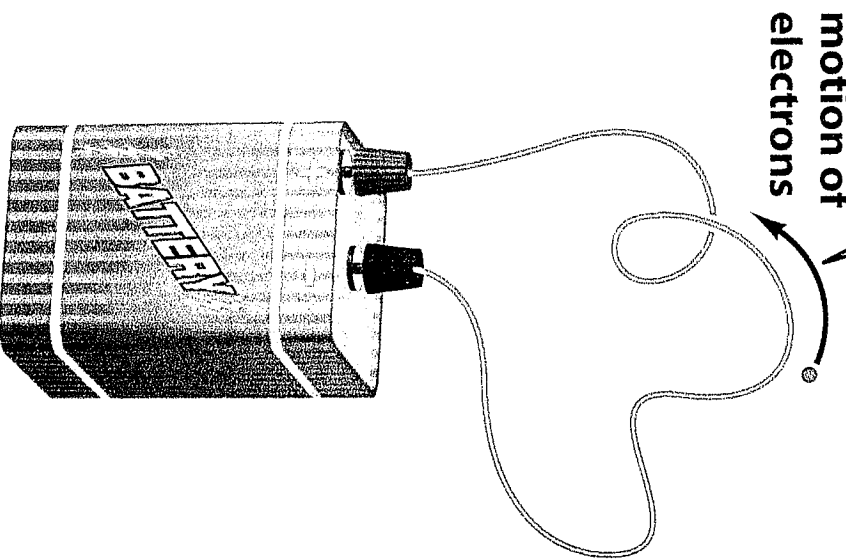
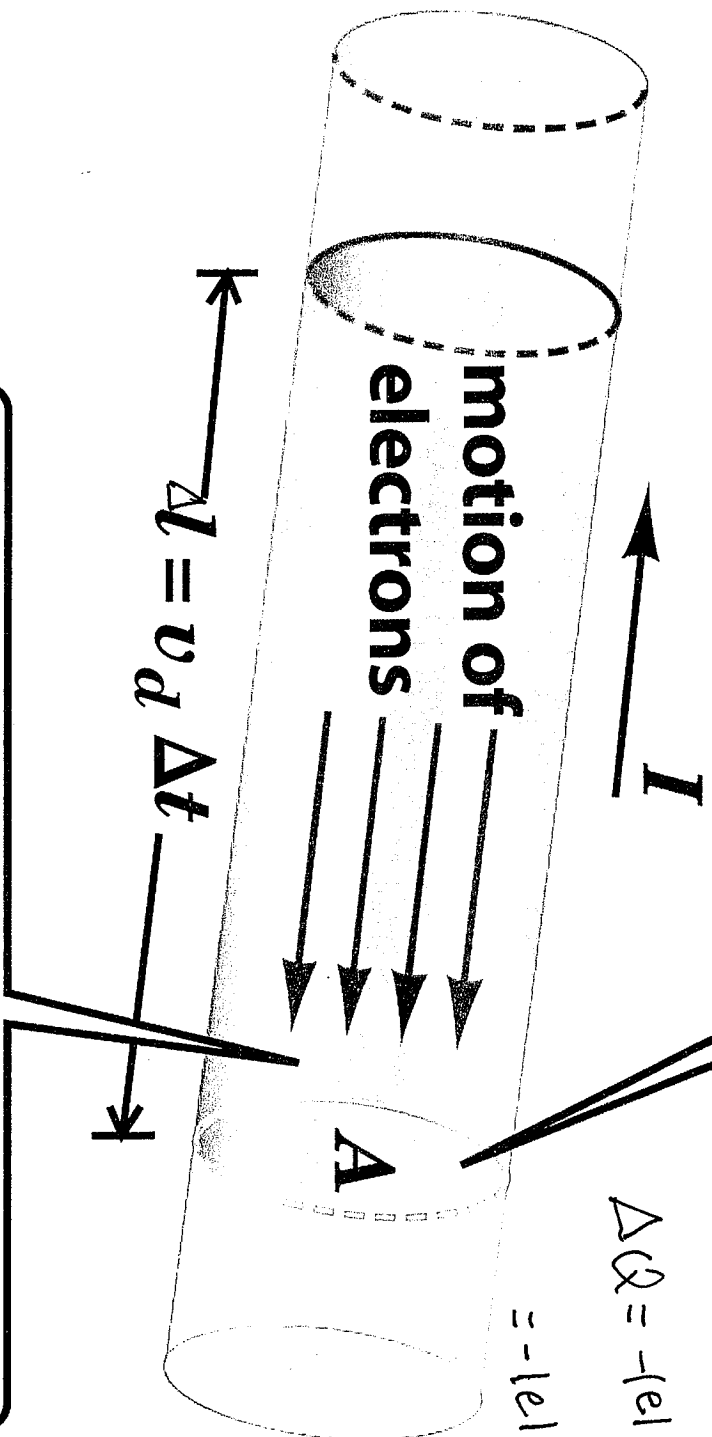


Figure 27-4 Physics for Engineers and Scientists 3/e  
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**Amount of charge that moves past area  $A$  in time  $\Delta t$ ...**



**...is the free charge in this volume  $A \times l = Av_d \Delta t$ .**

$$\Delta Q = -|e| n_e A v_d \Delta t$$

$$\frac{\Delta Q}{\Delta t} \rightarrow I$$

$$= |e| n_e v_d A$$

$$\equiv j A$$

$$I/A \equiv \text{current density}$$

$$\text{current} \equiv$$

$$\text{current density} \times \text{cross sectional area}$$

$$\frac{dQ}{dt} = j A$$

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Force on electrons

$$F_{mic} = -me v_e \dot{\tau}$$

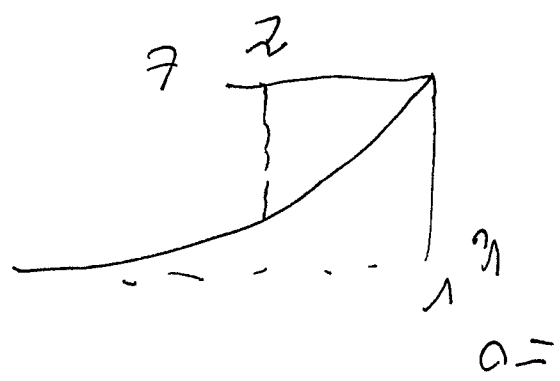
$\tau \equiv$  relaxation time.

In conductor electrons reach condition when zero force equals (balances) force

friction force

$$V_0 = -|e| E \tau$$

$$-me v_e \frac{dv_e}{dt} = -|e| E$$



electron current density =  $-N_e v_0$  (eliminate  $v_0$ )

$$= ne e^2 \tau E$$

$$\sigma E$$

$$j = ne^2 \tau E$$

$$\frac{j}{\text{electrical conductivity}} = \frac{me}{\dots}$$

$$\sigma = ne e^2 \tau$$

conductivity depends on substance and temperature

$$R = \frac{\rho_c d}{A}$$

$$\frac{1}{\sigma} = \rho_c$$

$$R = \frac{l}{Y} = \frac{d}{\sigma A} = \frac{m \tau}{q^2 n A}$$

$IR = V \equiv$  Ohm's law

$$I = JA = \left( \frac{d}{\sigma A} \right) V$$

$$J = \sigma E d = \sigma \frac{d}{\sigma} V$$

current density  $J = \sigma E = q^2 n \tau E$

$q \equiv$  charge of carrier

Ohm's law

$\rho = \text{electrical resistivity} = \frac{1}{\sigma} \equiv \text{ohm}\cdot\text{meter}$

**TABLE 27.2 RESISTIVITIES AND TEMPERATURE COEFFICIENTS OF RESISTANCE OF METALS<sup>a</sup>**

$$\rho = \rho_0 \left( \frac{T}{T_0} \right) + \alpha (T - T_0)$$

MATERIAL	$\rho$	$\alpha$
Silver	$1.6 \times 10^{-8} \Omega\cdot\text{m}$	$3.8 \times 10^{-3}/^\circ\text{C}$
Copper	$1.7 \times 10^{-8}$	$3.9 \times 10^{-3}$
Aluminum	$2.8 \times 10^{-8}$	$3.9 \times 10^{-3}$
Brass	$\approx 7 \times 10^{-8}$	$2 \times 10^{-3}$
Nickel	$7.8 \times 10^{-8}$	$6 \times 10^{-3}$
Iron	$10 \times 10^{-8}$	$5 \times 10^{-3}$
Steel	$\approx 11 \times 10^{-8}$	$4 \times 10^{-3}$
Constantan	$49 \times 10^{-8}$	$1 \times 10^{-5}$
Nichrome	$100 \times 10^{-8}$	$4 \times 10^{-4}$

<sup>a</sup> At a temperature of 20°C.

# TABLE 27.3

# RESISTIVITIES OF INSULATORS

MATERIAL	$\rho$
Polyethylene	$2 \times 10^{11} \Omega \cdot \text{m}$
Glass	$\approx 10^{12}$
Porcelain, unglazed	$\approx 10^{12}$
Rubber, hard	$\approx 10^{13}$
Epoxy	$\approx 10^{15}$

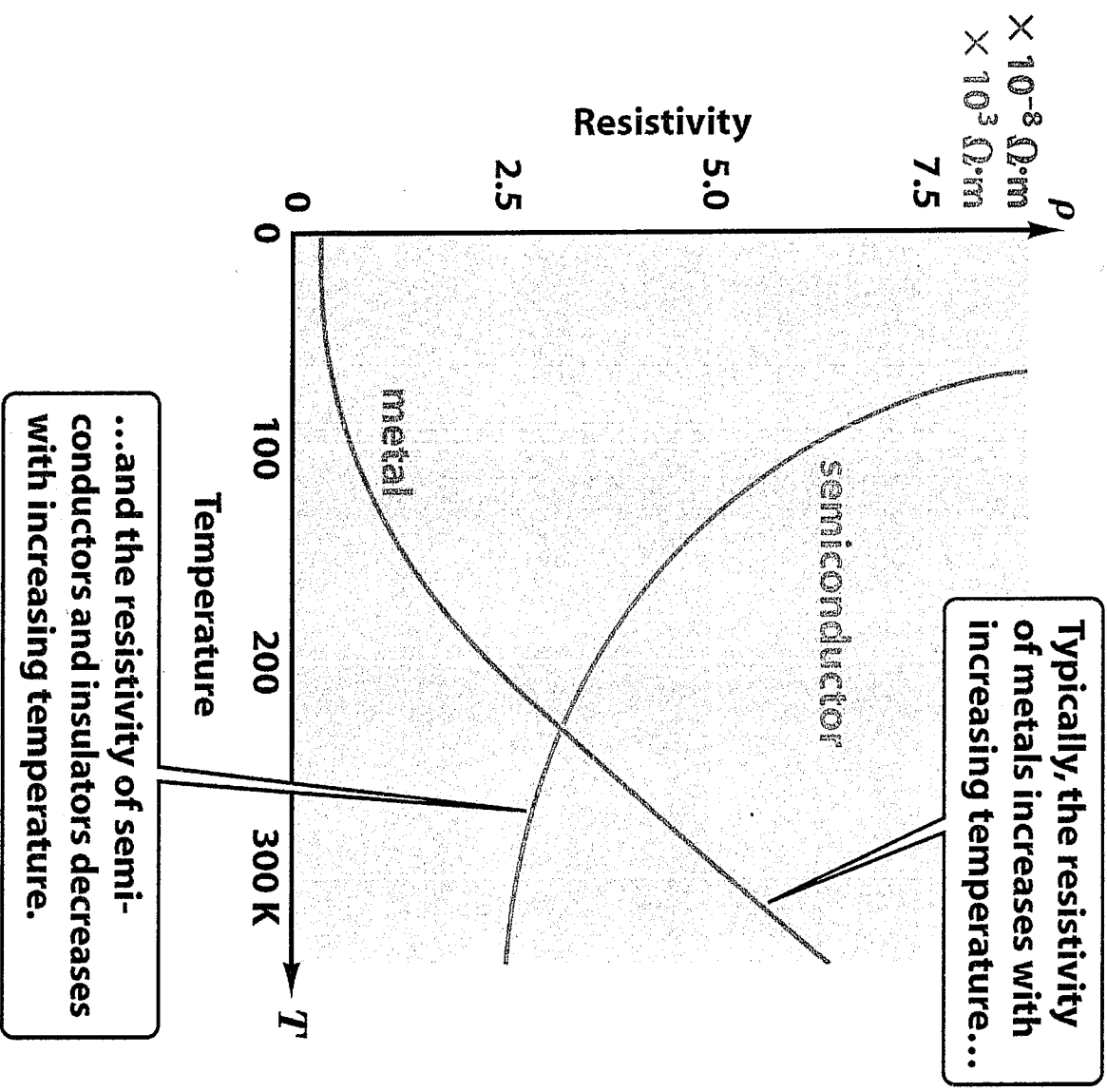


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**TABLE 27.4****RESISTIVITIES AND TEMPERATURE COEFFICIENTS OF RESISTANCE OF SEMICONDUCTORS<sup>a</sup>**

<b>MATERIAL</b>	$\rho$	$\alpha$
Carbon (graphite)	$3.5 \times 10^{-5} \Omega \cdot \text{m}$	$-5 \times 10^{-4} / ^\circ\text{C}$
Silicon	$2.6 \times 10^3$	$-8 \times 10^{-2}$
Germanium	$4.2 \times 10^{-1}$	$-5 \times 10^{-2}$

<sup>a</sup>At a temperature of 20°C.

**The resistance of a superconductor suddenly drops to zero at a critical temperature.**

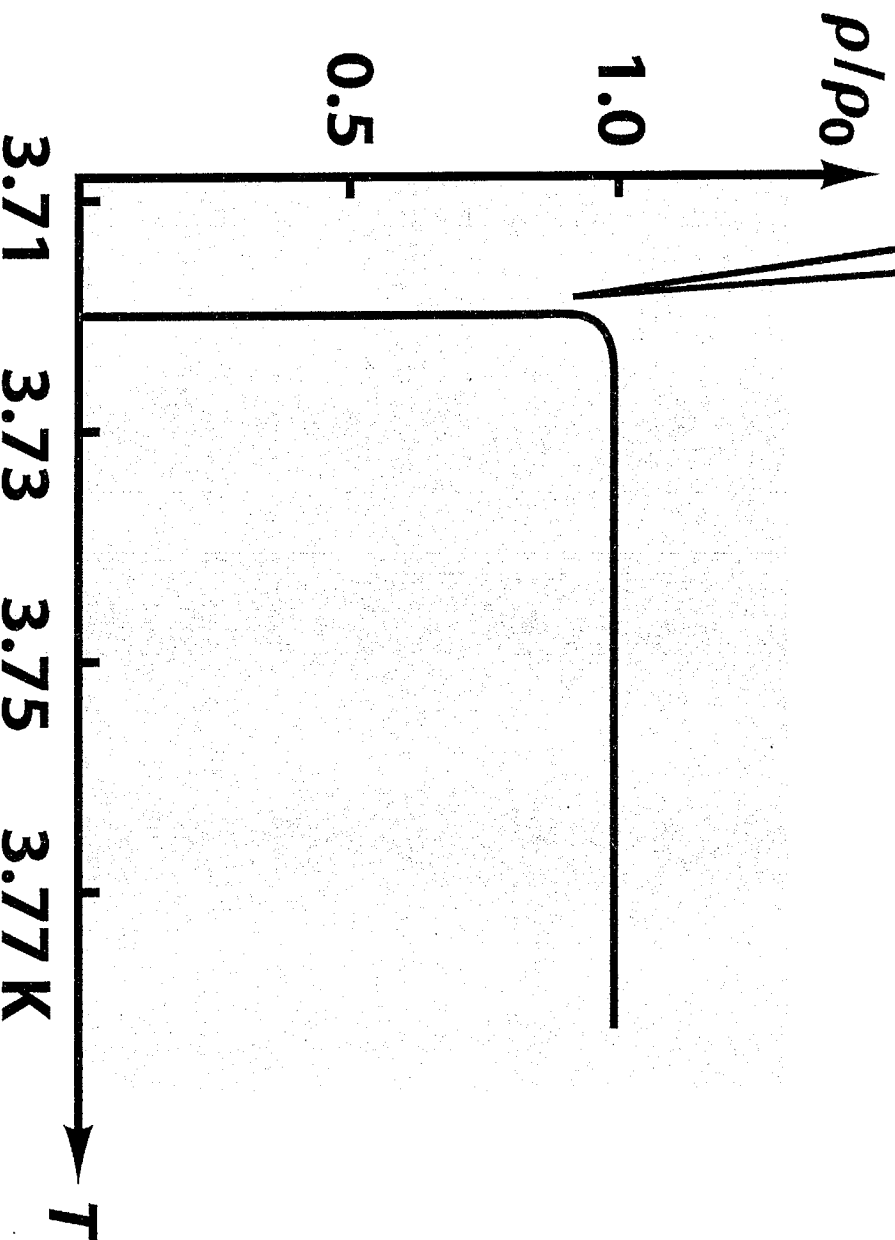


Figure 27-10 Physics for Engineers and Scientists 3/e  
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